Critical Detonation Thickness in Vapor-Deposited Pentaerythritol Tetranitrate (PETN) Films

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Topical Conference on Shock Compression of Condensed Matter,

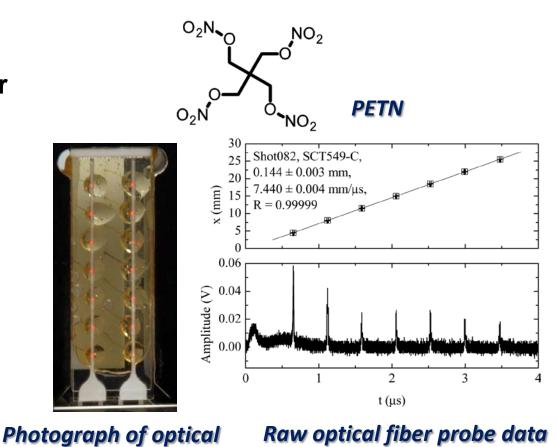
Chicago, IL, 26 June – 1 July, 2011.





Approach

- Thin PETN samples made by physical vapor deposition – different deposition conditions explored
- Detonation velocity measured for different deposition conditions by optical fiber probe technique
- Scanning electron microscopy used to analyze PETN cross-fiber probe on PETN film.

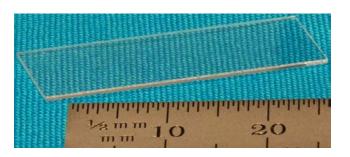


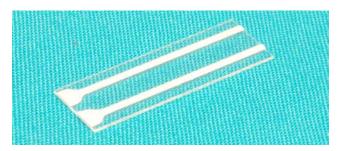
Raw optical fiber probe data and analyzed x-t data – used to determine detonation velocity.



Physical Vapor Deposition is Used to Make Small-Scale PETN Samples

- Physical vapor deposition is used to sublime/evaporate
 PETN from a hot source onto a cool substrate
- Substrates are 0.5 × 10.0 × 30.0 mm fused silica
- Shadow masks are used to pattern lines of PETN
 - 1.00 mm width used in this study
- Deposition time and amount of PETN in source controls thicknesses (0.112–0.202 μm)





Photograph of bare substrate next to substrate with deposited PETN films.





- Microstructure in vapor-deposited PETN is dependent on deposition conditions
 - Substrate material, substrate temperature, deposition rate
- Critical thickness for detonation is dependent on deposited film geometry
 - Deposited film width affects side losses during detonation propagation

Knepper, R., Tappan, A.S., Wixom, R.R., and Rodriguez, M.A., "Controlling the microstructure of vapor-deposited pentaerythritol tetranitrate films," *Journal of Materials Research*, in press, 2011 Tappan, A.S., Knepper, R., Wixom, R.R., Marquez, M.P., Miller, J.C., and Ball, J.P., "Critical Thickness Measurements in Vapor-Deposited Pentaerythritol Tetranitrate (PETN) Films," *14th International Detonation Symposium*, Coeur d'Alene, ID, April 11-16, 2010.



Deposition Conditions

- Four deposition conditions explored through differences in substrate cooling
- Previous work
 (International
 Detonation
 Symposium, 2010)
 involved lower cooling
 capacity and 0.80 mm
 wide lines

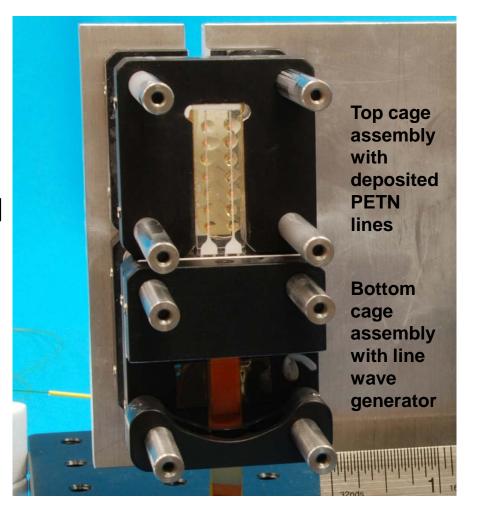
Substrate Cooling Capacity	Substrate Contact	Substrate Holder Temperature
		deg. C
Poor	N/A	N/A
Good	Poor	10
Good	Good	10
Good	Good	22



Detonation Velocity Measured as a Function of Deposition Thickness

- Film thickness measured using stylus surface profiler
- Critical thickness for detonation determined

Surface profiler data superimposed on cartoon of deposited PETN .



Critical thickness experiment.



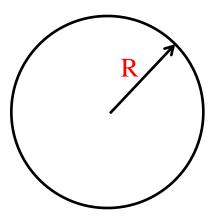
Data Analysis Is Conducted Using the **Standard Critical Diameter Form**

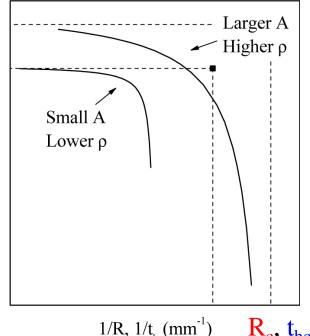
$$D(R) = D(\infty) \left[1 - \frac{1}{R} \left(\frac{A}{1 - R_c \frac{1}{R}} \right) \right] \qquad D(R) = D(\infty) \left[1 - \frac{1}{t_h} \left(\frac{A}{1 - t_{hc} \frac{1}{t_h}} \right) \right]$$

 $O(mm/\mu s)$

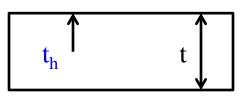
$$D(R) = D(\infty) \left| 1 - \frac{1}{t_h} \left(\frac{A}{1 - t_{hc} \frac{1}{t_h}} \right) \right|$$

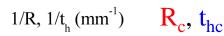
$D(\infty)$ Critical diameter configuration.





Critical thickness configuration.





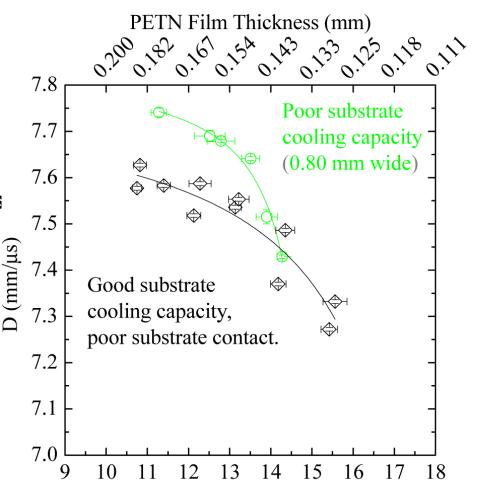


Critical Thickness Comparison – Substrate Cooling Capacity

- Higher substrate cooling capacity:
 - Smaller critical thickness
 - Lower infinite velocity less dense

 Larger length param. – less homogeneous

Detonation Velocity at Infinite Thickness, D(∞)	Critical Thickness, t₀	Length Parameter, A
mm/μs	mm	mm
7.82 ± 0.05	0.131 ± 0.003	0.0002 ± 0.0001
7.72 ± 0.10	0.107 ± 0.014	0.0006 ± 0.0005



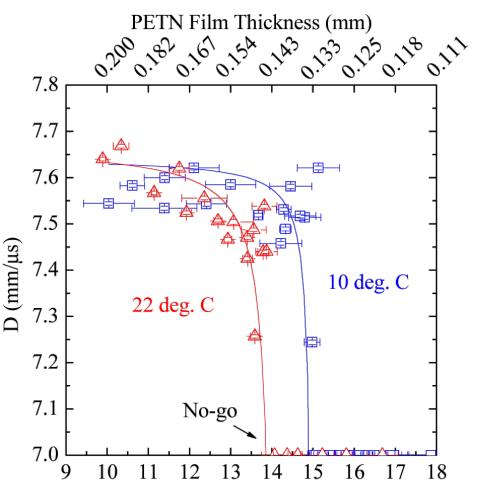
1/PETN Half Thickness (mm⁻¹)



Critical Thickness Comparison – Substrate Temperature

- Lower substrate temperature:
 - Smaller critical thickness
 - Similar infinite velocity
 - Smaller length param. more homogeneous

Detonation Velocity at Infinite Thickness, D(∞)	Critical Thickness, t _c	Length Parameter, A
mm/μs	mm	mm
7.64 ± 0.28	0.133 ± 0.000	0.00004 ± 0.00004
7.66 ± 0.28	0.142 ± 0.000	0.0004 0.0001 ± 0.00004



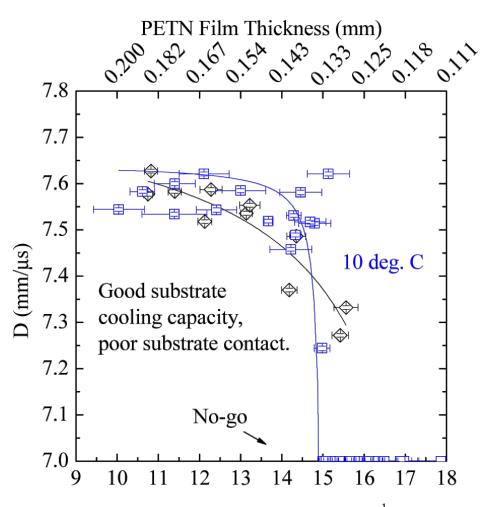
1/PETN Half Thickness (mm⁻¹)



Critical Thickness Comparison – Substrate Contact

- Better substrate contact with cooling block:
 - Larger critical thickness
 - Similar infinite velocity
 - Smaller length param. more homogeneous

Detonation Velocity at Infinite Thickness, D(∞)	Critical Thickness, t _c	Length Parameter, A
mm/μs	mm	mm
7.64 ± 0.28	0.133 ± 0.000	0.00004 ± 0.00004
7.72 ± 0.10	0.107 ± 0.014	0.0006 ± 0.0005

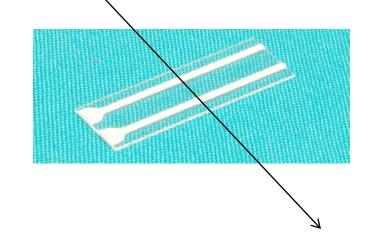


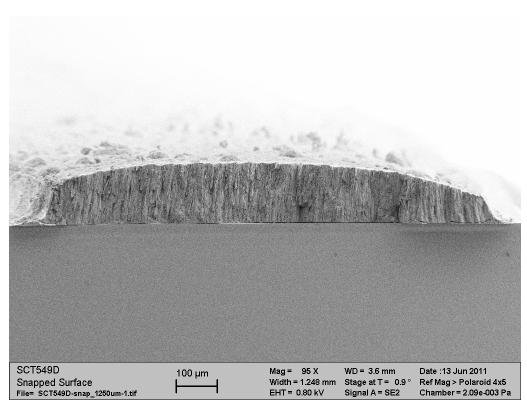
1/PETN Half Thickness (mm⁻¹)



PETN Films Are Snapped for SEM Analysis of Cross-Section

Fused silica
 substrates are
 broken across
 scribe line

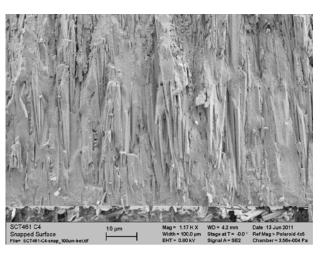




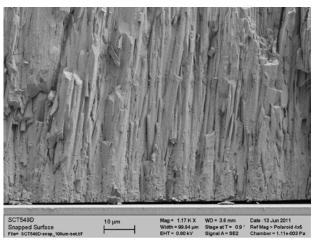
Scanning electron micrograph of cross-sectioned PETN film on fused silica substrate.



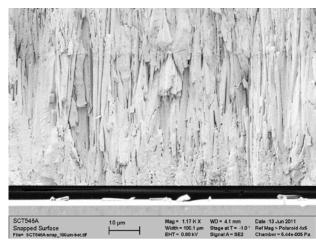
Microstructure does not show obvious differences with deposition conditions



SEM of PETN, Poor substrate cooling capacity.



SEM of PETN, Good substrate cooling capacity, 22 ℃.



SEM of PETN, Good substrate cooling capacity, 10 ℃.



Conclusions

- Deposition conditions affect critical thickness behavior of vapor deposited PETN
- Higher cooling capacity of substrate holder:
 - Smaller critical thickness and smaller infinite velocity
- Lower substrate temperature:
 - Smaller critical thickness
 - Similar infinite velocity
- Better substrate contact with cooling block:
 - Larger critical thickness
 - Similar infinite velocity
 - Smaller length parameter more homogeneous
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